

L Number	Hits	Search Text	DB	Time stamp
1	637	migrat\$3 with etch\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/05 16:13
2	429	(migrat\$3 with etch\$3) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/05 16:13
3	13	((migrat\$3 with etch\$3) and semiconductor) and (thin near film near transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/05 16:14
-	459	((438/149) or (438/479)).CCLS.	USPAT	2003/06/05 16:13
-	1277	((438/149) or (438/479) or (438/517) or (438/151) or (438/473) or (438/476) or (438/486) or (438/487) or (438/491)).CCLS.	USPAT	2000/09/21 14:38
-	139	((("438/149") or ("438/479") or ("438/517") or ("438/151") or ("438/473") or ("438/476") or ("438/486") or ("438/487") or ("438/491"))).CCLS.) and (nickle or Ni)	USPAT	2000/09/21 14:39
-	102	(((("438/149") or ("438/479") or ("438/517") or ("438/151") or ("438/473") or ("438/476") or ("438/486") or ("438/487") or ("438/491"))).CCLS.) and (nickle or Ni)) and (irradiat\$)	USPAT	2000/09/21 14:39
-	12	(((((("438/149") or ("438/479") or ("438/517") or ("438/151") or ("438/473") or ("438/476") or ("438/486") or ("438/487") or ("438/491"))).CCLS.) and (nickle or Ni)) and (irradiat\$)) and (phosph\$)	USPAT	2000/09/22 08:55
-	4	((("5594569") or ("5643826") or ("5923962") or ("5854096"))).PN.	USPAT	2000/09/22 09:56
-	170	((yamazaki adj shunpei).in.) and nickel	USPAT	2000/09/22 09:57
-	29	((yamazaki adj shunpei).in.) and nickel) and getter\$	USPAT	2000/09/22 09:57
-	26	((yamazaki adj shunpei).in.) and nickel) and phosphor\$	USPAT	2000/09/22 09:58
-	78	((yamazaki adj shunpei).in.) and nickel) and (TFT or (thin adj flim adj transistor))	USPAT	2000/09/22 09:59
-	78	((((yamazaki adj shunpei).in.) and nickel) and (TFT or (thin adj flim adj transistor))) and method	USPAT	2000/09/22 10:00
-	17	(((((yamazaki adj shunpei).in.) and nickel) and (TFT or (thin adj flim adj transistor))) and method) and phosphor\$	USPAT	2000/09/22 10:00
-	3088	(yamazaki adj shunpei).in.	USPAT; JPO; IBM_TDB	2000/09/22 11:05
-	280	((yamazaki adj shunpei).in.) and nickel	USPAT; JPO; IBM_TDB	2000/09/22 11:05
-	47	((yamazaki adj shunpei).in.) and nickel) and getter\$	USPAT; JPO; IBM_TDB	2000/09/22 11:06
-	11	((((yamazaki adj shunpei).in.) and nickel) and getter\$) and phosphor\$	USPAT; JPO; IBM_TDB	2000/09/22 11:08
-	172	((438/482) or (438/150)).CCLS.	USPAT	2000/09/22 12:38
-	37	((("438/482") or ("438/150"))).CCLS.) and TFT	USPAT	2000/09/22 12:38
-	9	((("5854096") or ("5712191") or ("5696386") or ("5960323") or ("5643826") or ("6093937") or ("6121076") or ("5616506") or ("5888857")).PN.	USPAT	2000/09/25 13:31
-	2	((("5594569") or ("5923962"))).PN.	USPAT	2001/04/16 08:42

	0	(Ni or nickel or metal) with (UV or ultraviolet or IR or infrared) with (amorphous adj silicon) with TFT	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/04/16 08:43
	41	(Ni or nickel or metal) with (UV or ultraviolet or IR or infrared) with (amorphous adj silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/04/16 08:43
	13	(Ni or nickel or metal) with (UV or ultraviolet or IR or infrared) with (amorphous adj silicon) and TFT	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/04/16 08:50
	81	TFT and (Si adj Ge)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/04/16 08:50
	37	((TFT and (Si adj Ge)) and Ni	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/04/16 08:59
	27	((TFT and (Si adj Ge)) and Ni) and (UV or IR or ultraviolet or infrared)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/04/16 09:03
	114	TFT and SiGe	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/04/16 09:03
	20	((TFT and SiGe) and Ni	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/04/16 09:04
	40	((TFT and SiGe) and (UV or IR or ultraviolet or infrared)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/04/16 09:04
	15	((TFT and SiGe) and Ni) and (UV or IR or ultraviolet or infrared)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/04/16 09:07
	11	TFT with SiGe	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/04/16 09:07
	1	("6093937").PN.	USPAT	2001/04/16 12:57
	4	("5569610").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2001/10/10 16:17
	0	(peabody).at.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/10/10 16:17
	893	(peabody).att.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/10/10 16:17
	796	(yamazaki adj shunpei).in.	USPAT	2001/10/10 16:19
	23	Freidman.att.	USPAT	2001/10/10 16:19

-	9412	(fish with richardson).att.	USPAT	2001/10/10 16:19
-	0	((fish with richardson).att.) and ((semiconductor adj energy adj lab).as.)	USPAT	2001/10/10 16:21
-	217	((fish with richardson).att.) and ((semiconductor adj energy adj laboratory).as.)	USPAT	2001/10/10 16:22
-	29	(((fish with richardson).att.) and ((semiconductor adj energy adj laboratory).as.)) and (catalytic and laser)	USPAT	2001/10/11 08:59
-	1	Friedman.att. and (catalytic and laser)	USPAT	2001/10/10 16:22
-	36	((peabody).att.) and (catalytic and laser)	USPAT	2001/10/11 08:48
-	9	((peabody).att.) and (catalytic and laser) and (remove with oxide)	USPAT	2001/10/11 09:04
-	0	((peabody).att.) and (catalytic and laser) and (remove with oxide) and levling	USPAT	2001/10/11 08:57
-	0	((peabody).att.) and (catalytic and laser) and (remove with oxide) and leveling	USPAT	2001/10/11 08:58
-	0	((peabody).att.) and (catalytic and laser) and (remove with oxide) and planarize	USPAT	2001/10/11 08:59
-	3	(((fish with richardson).att.) and ((semiconductor adj energy adj laboratory).as.)) and (catalytic and laser) and (planarize or leveling or flatten or smoothen)	USPAT	2001/10/11 08:59
-	1	((peabody).att.) and (catalytic and laser) and (remove with oxide) and ((planarize or planarization or planarized or flat or flatten or flaten or flattened or leveling or level or smooth or smoothen) with (heat or thermal or heated or heating))	USPAT	2001/10/11 09:05
-	52	TFT and (laser with (air or oxygen) with (crystallization or crystallized or crystalized or crystal))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/31 09:11
-	18	TFT and (laser with (air) with (crystallization or crystallized or crystalized or crystal))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/31 09:12